HD30996
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Rack mounted system
Class AB linear LDMOS design
Instantaneous bandwidth
Designed for high power UHF applications
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	450 - 550 MHz	
Power Output	100W Min	CW
Power Gain	50 dB Min	
Power Gain Flatness	2.0 dB p-p Max	Constant input power
Input Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30 dBc Typ	40dBm/Tone, Δ = 1MHz
Harmonics	<-20 dBc Typ	At rated output power
Non Harmonics Spurious	-60dBc Max	
Operating Voltage	100 - 240 VAC	
Power Consumption	400 Watt Max	At rated Pout
Input Power Protection	+10 dBm Max	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

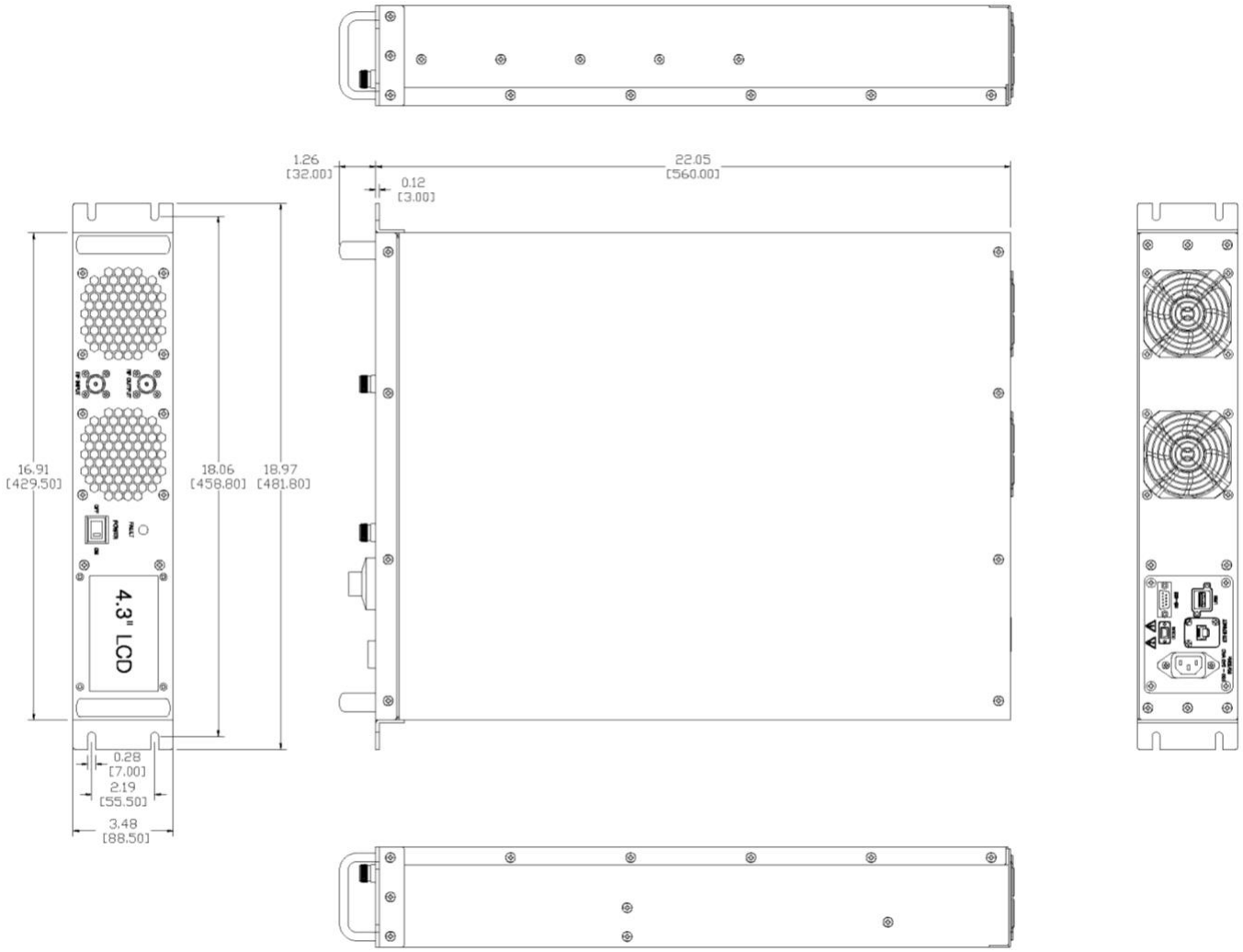
MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 89 x 562 mm	2U - Excluding connectors
Weight	12 kg.	
RF Connectors In / Out	Type-N Female	Front or rear panel
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	Remote Bluetooth application

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OUTLINE DRAWING



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